



IRFB4510GPBF Information

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For Reference Only

Part Number IRFB4510GPBF
Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N CH 100V 62A TO-220AB

Package TO-220-3

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









IRFB4510GPBF Specifications

Manufacturer Part Number	IRFB4510GPBF
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	HEXFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	62A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 100μA
Gate Charge (Qg) (Max) @ Vgs	87nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3180pF @ 50V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	140W (Tc)
Rds On (Max) @ Id, Vgs	13.5 mOhm @ 37A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-220AB
Package / Case	TO-220-3
	Report errors?

IRFB4510GPBF Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFB4510GPBF Payment Methods





















IRFB4510GPBF Shipping Methods













If you have any question about IRFB4510GPBF, please do not hesitate to contact us!

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